TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (π-MOSV)

# 2SK3437

# DC-DC Converter, Relay Drive and Motor Drive Applications

- Low drain-source ON-resistance:  $R_{DS (ON)} = 0.74 \Omega (typ.)$
- High forward transfer admittance: |Y<sub>fs</sub>| = 4.5 S (typ.)
- Low leakage current: I<sub>DSS</sub> = 100 μA (max) (V<sub>DS</sub> = 600 V)
- Enhancement mode:  $V_{th}$  = 3.0 to 5.0 V ( $V_{DS}$  = 10 V,  $I_D$  = 1 mA)

## **Absolute Maximum Ratings (Ta = 25°C)**

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		$V_{DSS}$	600	V	
Drain-gate voltage ( $R_{GS} = 20 \text{ k}\Omega$ )		$V_{DGR}$	600	V	
Gate-source voltage		$V_{GSS}$	±30	V	
Drain current	DC (Note 1)	ΙD	10	А	
	Pulse (Note 1)	I <sub>DP</sub>	30		
Drain power dissipation	(Tc = 25°C)	P <sub>D</sub>	80	W	
Single pulse avalanche energy (Note 2)		E <sub>AS</sub>	252	mJ	
Avalanche current		I <sub>AR</sub>	10	Α	
Repetitive avalanche energy (Note 3)		E <sub>AR</sub>	8	mJ	
Channel temperature	T <sub>ch</sub>	150	°C		
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Thermal Characteristics**

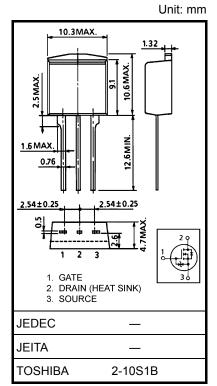
Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R <sub>th (ch-c)</sub>	1.56	°C/W
Thermal resistance, channel to ambient	R <sub>th (ch-a)</sub>	83.3	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

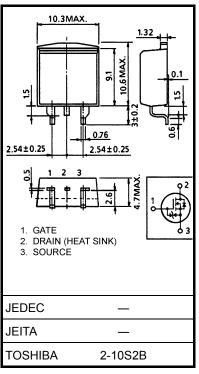
Note 2:  $V_{DD} = 90~V,~T_{ch} = 25^{\circ}C$  (initial), L = 4.41 mH, R<sub>G</sub> = 25  $\Omega$ ,  $I_{AR} = 10~A$ 

Note 3: Repetitive rating: Pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Please handle with caution.



Weight: 1.5 g (typ.)



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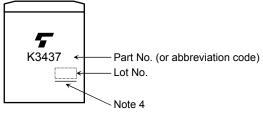
#### **Electrical Characteristics (Ta = 25°C)**

Chara	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GSS</sub>	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±10	μА
Gate-source brea	kdown voltage	V (BR) GSS	$I_G = \pm 10 \ \mu A, \ V_{DS} = 0 \ V$	±30	_	_	V
Drain cut-off current		I <sub>DSS</sub>	V <sub>DS</sub> = 600 V, V <sub>GS</sub> = 0 V	_	_	100	μА
Drain-source breakdown voltage		V (BR) DSS	$I_D = 10$ mA, $V_{GS} = 0$ V	600	_	_	V
Gate threshold voltage		V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	3.0	_	5.0	V
Drain-source ON-resistance		R <sub>DS</sub> (ON)	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 5 A	_	0.74	1.0	Ω
Forward transfer a	sfer admittance $ Y_{fS} $ $V_{DS} = 15 \text{ V}, I_D = 5 \text{ A}$		V <sub>DS</sub> = 15 V, I <sub>D</sub> = 5 A	2.0	4.5	_	S
Input capacitance		C <sub>iss</sub>		_	1200	_	pF
Reverse transfer capacitance		C <sub>rss</sub>	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	_	10	_	
Output capacitance		Coss		_	130	_	
Switching time	Rise time	t <sub>r</sub>	$\begin{array}{c} \text{10 V} \\ \text{VGS} \\ \text{0 V} \\ \end{array} \begin{array}{c} \text{I}_{D} = 5 \text{ A} \\ \text{VOUT} \\ \text{O} \\ \end{array} \\ \begin{array}{c} \text{RL} = 60 \ \Omega \\ \text{VDD} \approx 300 \ V \\ \end{array}$ Duty $\leq$ 1%, $t_{W} = 10 \ \mu s$		13	_	- ns
	Turn-on time	t <sub>on</sub>			40	_	
	Fall time	t <sub>f</sub>			8	_	
	Turn-off time	t <sub>off</sub>		_	50	_	
Total gate charge (gate-source plus gate-drain)		Qg		_	28	_	nC
Gate-source charge		Q <sub>gs</sub>	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 10 \text{ A}$	_	16	_	
Gate-drain ("miller") charge		Q <sub>gd</sub>		_	12	_	

### **Source-Drain Ratings and Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	$I_{DR}$	_	_	_	10	Α
Pulse drain reverse current (Note 1)	I <sub>DRP</sub>	_	_	_	30	Α
Forward voltage (diode)	$V_{DSF}$	I <sub>DR</sub> = 10 A, V <sub>GS</sub> = 0 V	_	_	-1.7	٧
Reverse recovery time	t <sub>rr</sub>	$I_{DR} = 10 \text{ A}, V_{GS} = 0 \text{ V},$	_	1600		ns
Reverse recovery charge	Q <sub>rr</sub>	dI <sub>DR</sub> /dt = 100 A/μs		17	_	μС

#### Marking

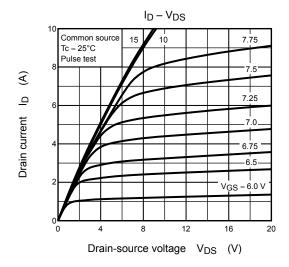


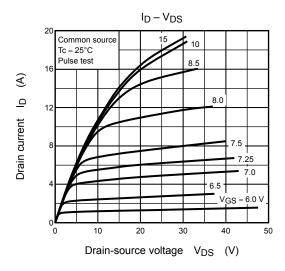
Note 4: A line under a Lot No. identifies the indication of product Labels.

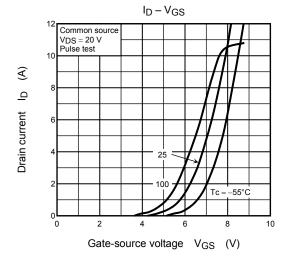
Not underlined: [[Pb]]/INCLUDES > MCV

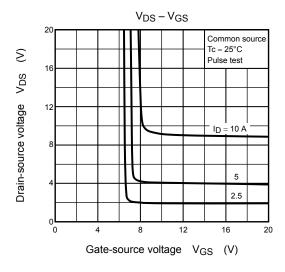
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

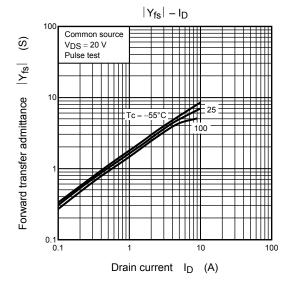
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

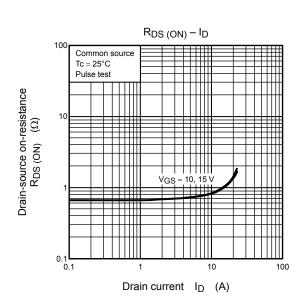




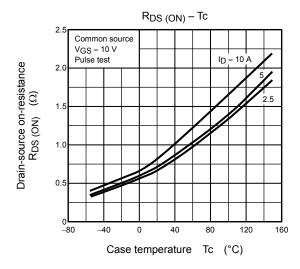


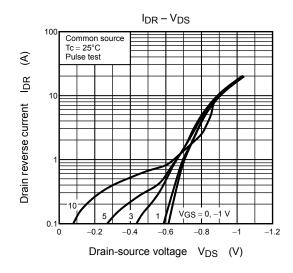


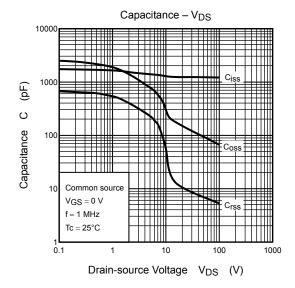


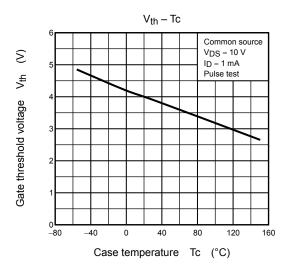


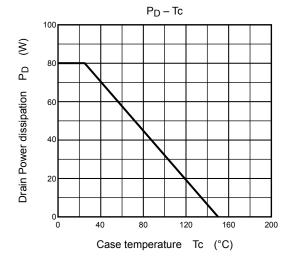
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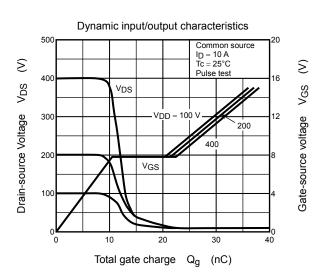


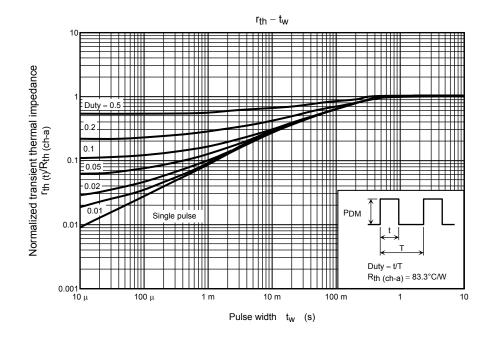


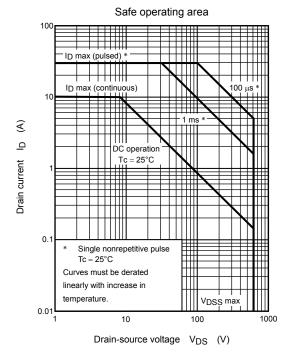


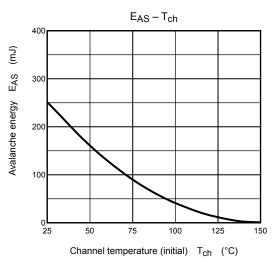


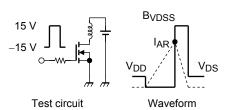












$$\begin{aligned} &R_G = 25~\Omega \\ &V_{DD} = 90~V,~L = 4.41~mH \end{aligned} \qquad E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left( \frac{BVDSS}{BVDSS - VDD} \right) \cdot \frac{1}{2} \cdot \frac{1}{2}$$

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